Application No.: NEW Docket No.: 5376-0101PUS1

AMENDMENTS TO THE CLAIMS

1. (Original) A cleaner that is an aqueous solution containing phosphoric acid, hydrofluoric acid, and ammonia and/or amine and having a pH ranging from 2 to 12, wherein said aqueous solution contains:

- 0.5 to 25 mass% of phosphoric acid,
- 0.1 to 10 mass% of ammonia and/or amine, and
- 5×10^{-3} to 5.0 mass% of hydrofluoric acid.
- 2. (Original) The cleaner according to claim 2, wherein the pH is regulated by phosphoric acid.
- 3. (Original) The cleaner according to claim 1 or 2, which further includes a surface active agent and/or a chelate agent.
- 4. (Currently amended) The clearer according to any one of claims 1 to 3 claim 1, which further includes hydrogen peroxide.
- 5. (Currently amended) The cleaner according to any one of claims 1 to 4 claim 1, which is used for cleaning off particles and/or metal impurities out of the surface of a semiconductor device substrate.
- 6. (New) The clearer according to claim 2, which further includes hydrogen peroxide.
- 7. (New) The clearer according to claim 3, which further includes hydrogen peroxide.
- 8. (New) The cleaner according to claim 2, which is used for cleaning off particles and/or metal impurities out of the surface of a semiconductor device substrate.

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9. (New) The cleaner according to claim 3, which is used for cleaning off particles and/or metal impurities out of the surface of a semiconductor device substrate.

10. (New) The cleaner according to claim 4, which is used for cleaning off particles and/or metal impurities out of the surface of a semiconductor device substrate.

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